

SN75LBC978 9-CHANNEL DIFFERENTIAL TRANSCIVER

SLLS134E – APRIL 1992 – REVISED MAY 1997

- **Nine Differential Channels for the Data and Control Paths of the Differential Small Computer Systems Interface (SCSI)**
- **Meets or Exceeds the Requirements of ANSI Standard RS-485 and ISO 8482:1987(E)**
- **Packaged in Shrink Small-Outline Package With 25-mil Terminal Pitch**
- **Designed to Operate at 10 Million Transfers Per Second**
- **Low Disabled Supply Current
1.4 mA Typ**
- **Thermal Shutdown Protection**
- **Power-Up/Power-Down Glitch Protection**
- **Positive and Negative Output-Current Limiting**
- **Open-Circuit Fail-Safe Receiver Design**

description

The SN75LBC978 is a nine-channel differential transceiver based on the 75LBC176 LinASIC™ cell. Use of TI's LinBiCMOS™† process technology allows the power reduction necessary to integrate nine differential balanced transceivers†. On-chip enabling logic makes this device applicable for the data path (eight data bits plus parity) and the control path (nine bits) for the Small Computer Systems Interface (SCSI) standard. The WRAP function allows in-circuit testing and wired-OR channels for the BSY, RST, and SEL signals of the SCSI bus.

The SN75LBC978 is packaged in a shrink small-outline package (DL) with improved thermal characteristics using heat-sink terminals. This package is ideal for low-profile, space-restricted applications such as hard disk drives.

The switching speed of the SN75LBC978 is sufficient to transfer data over the data bus at 10 million transfers per second. Each of the nine identical channels conforms to the requirements of the ANSI RS-485 and ISO 8482:1987(E) standards referenced by ANSI X3.131-1993 (SCSI-2) and the proposed SCSI-3 standards.

The SN75LBC978 is characterized for operation from 0°C to 70°C.

DL PACKAGE
(TOP VIEW)

NC	1	56	NC
WRAP2	2	55	NC
WRAP1	3	54	CE
1A	4	53	9B+
1DE/RE	5	52	9B-
2A	6	51	8B+
2DE/RE	7	50	8B-
3A	8	49	7B+
3DE/RE	9	48	7B-
4A	10	47	6B+
4DE/RE	11	46	6B-
V _{CC}	12	45	V _{CC}
GND	13	44	GND
GND	14	43	GND
GND	15	42	GND
GND	16	41	GND
GND	17	40	GND
V _{CC}	18	39	V _{CC}
5A	19	38	5B+
5DE/RE	20	37	5B-
6A	21	36	4B+
6DE/RE	22	35	4B-
7A	23	34	3B+
7DE/RE	24	33	3B-
8A	25	32	2B+
8DE/RE	26	31	2B-
9A	27	30	1B+
9DE/RE	28	29	1B-

Pins 13 through 17 and 40 through 44 are connected together to the package lead frame and signal ground.

† Patent Pending

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



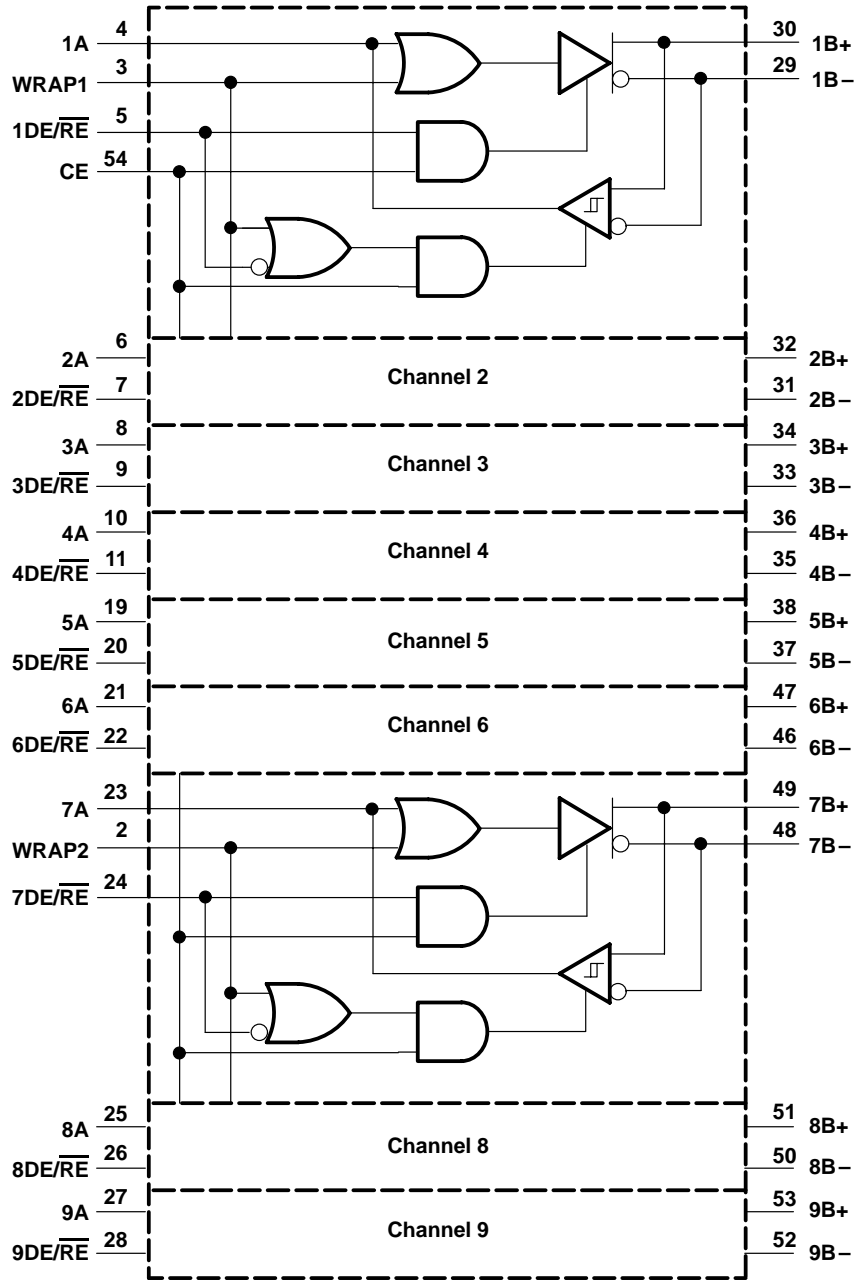
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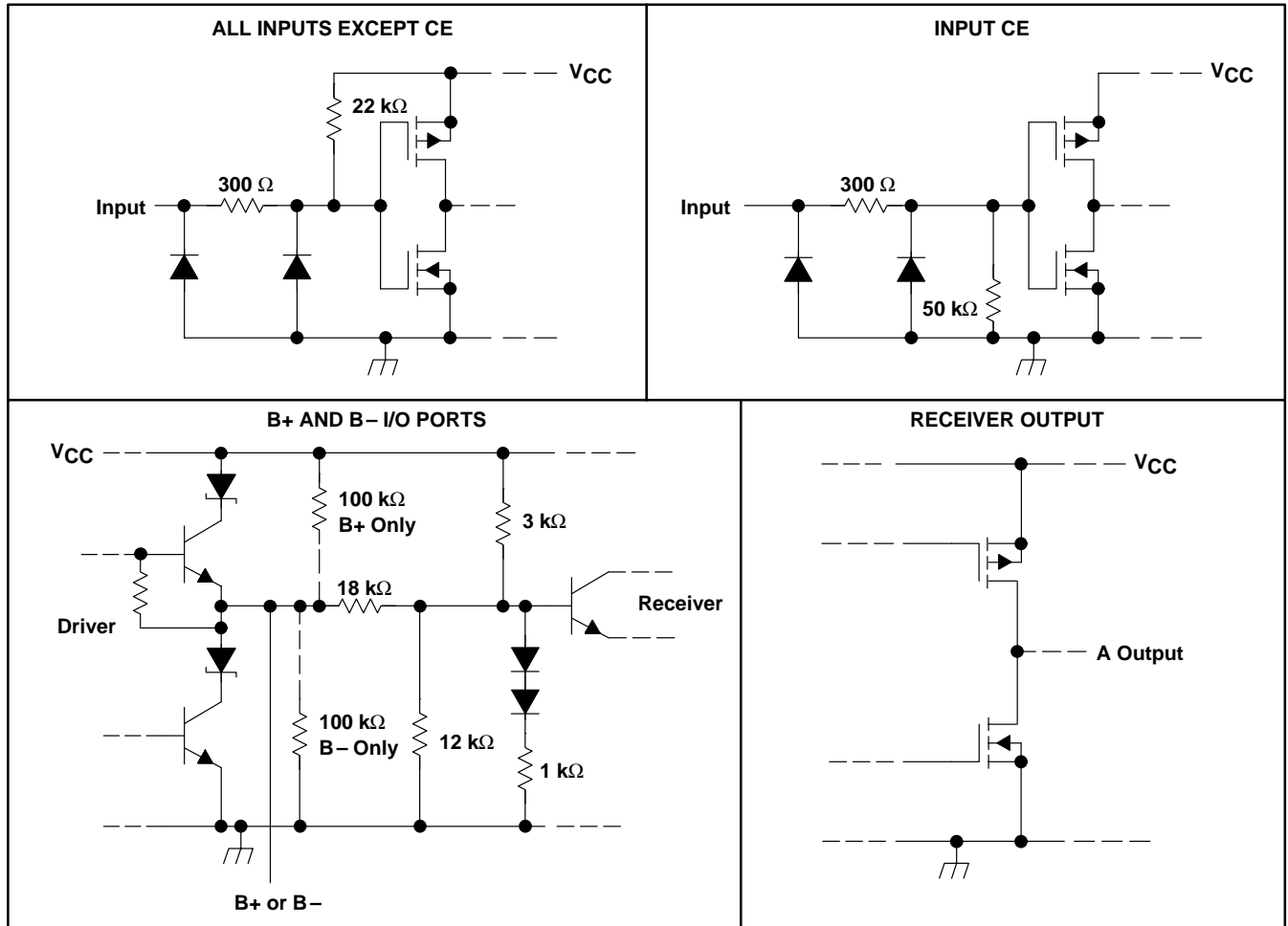
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logic diagram (positive logic)



schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} (see Note 1)	–0.3 V to 7 V
Bus voltage range	–10 V to 15 V
Data I/O and control (A-side) voltage range	–0.3 V to 7 V
Continuous power dissipation	internally limited
Operating free-air temperature range, T_A	0°C to 70°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are dc and with respect to GND.

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recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.75	5	5.25	V
Voltage at any bus terminal (separately or common-mode), V_O , V_I , or V_{IC}	B+ or B-	12			V
		-7			
High-level input voltage, V_{IH}	All except B+ and B-	2			V
Low-level input voltage, V_{IL}	All except B+ and B-			0.8	V
High-level output current, I_{OH}	B+ or B-			-60	mA
	A			-8	mA
Low-level output current, I_{OL}	B+ or B-			60	mA
	A			8	mA
Operating free-air temperature, T_A		0		70	°C

device electrical characteristics over recommended ranges of operating conditions

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
I_{IH}	High-level input current	A, WRAP, DE/ \overline{RE}	See Figure 1	$V_{IH} = 2\text{ V}$		-200	μA
		CE				100	μA
I_{IL}	Low-level input current	A, WRAP, DE/ \overline{RE}	See Figure 1	$V_{IL} = 0.8\text{ V}$		-200	μA
		CE				100	μA
I_{CC}	Supply current	All drivers and receivers disabled	CE at 0 V		1.4	3	mA
		All receivers enabled	No load, CE at 5 V,	$V_{ID} = 5\text{ V}$, WRAP and DE/ \overline{RE} at 0 V	29	45	mA
		All drivers enabled	No load, WRAP at 0 V	CE and DE/ \overline{RE} at 5 V,	7	10	mA
C_O	Bus port output capacitance	B+ or B-			19		pF
C_{pd}	Power dissipation capacitance	One driver			460		pF
		One receiver			40		pF

driver electrical characteristics over recommended ranges of operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$ V_{OD} $	Differential output voltage	$V_{test} = -7\text{ V to }12\text{ V}$, See Figure 2		1	2		V
I_{OS}	Output short-circuit current	See Figure 3				± 250	mA
I_{OZ}	High-impedance-state output current	See receiver input current					



receiver electrical characteristics over recommended ranges of operating conditions (unless otherwise noted) (see Figure 3)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT	
V _{OH}	High-level output voltage	V _{ID} = 200 mV, I _{OH} = -8 mA	2.5			V	
V _{OL}	Low-level output voltage	V _{ID} = -200 mV, I _{OL} = 8 mA			0.8	V	
V _{IT+}	Differential-input high-level threshold voltage	I _{OH} = -8 mA			0.2	V	
V _{IT-}	Differential-input low-level threshold voltage	I _{OL} = 8 mA	-0.2			V	
V _{hys}	Receiver input hysteresis voltage (V _{IT+} - V _{IT-})			45		mV	
I _I	Receiver input current	B+ and B-	V _I = 12 V, V _{CC} = 5 V, Other input at 0 V		0.7	1	mA
			V _I = 12 V, V _{CC} = 0 V, Other input at 0 V		0.8	1	mA
			V _I = -7 V, V _{CC} = 5 V, Other input at 0 V		-0.5	-0.8	mA
			V _I = -7 V, V _{CC} = 0 V, Other input at 0 V		-0.4	-0.8	mA
I _{OZ}	High-impedance-state output current	V _O = GND			-200	μA	
		V _O = V _{CC}			50		

driver switching characteristics over recommended ranges of operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t _d (OD)	Differential delay time, high- to low-level output (t _d (ODH)) or low- to high-level output (t _d (ODL))	See Figure 4	11.8		26.4	ns
		V _{CC} = 5 V, T _A = 25°C, See Figure 4	14	18	22	
		V _{CC} = 5 V, T _A = 70°C, See Figure 4	18	22	26	
t _{sk} (lim)	Skew limit, the maximum difference in propagation delay times between any two drivers on any two devices				15	ns
		V _{CC} = 5 V, See Note 2			8	
t _{sk} (p)	Pulse skew (t _d (ODL) - t _d (ODH))			0	6	ns
t _t	Transition time (t _r or t _f)	See Figure 4		10		ns

receiver switching characteristics over recommended ranges of operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t _{pd}	Propagation delay time, high- to low-level output (t _{PHL}) or low- to high-level output (t _{PLH})	See Figure 5	19.5		30.7	ns
		V _{CC} = 5 V, T _A = 25°C, See Figure 5	20.2	24.7	29.2	
		V _{CC} = 5 V, T _A = 70°C, See Figure 5	21.1	25.6	30.1	
t _{sk} (lim)	Skew limit, the maximum difference in propagation delay times between any two drivers on any two devices				12	ns
		V _{CC} = 5 V, See Note 2			9	
t _{sk} (p)	Pulse skew (t _{PHL} - t _{PLH})			2	6	ns
t _t	Transition time (t _r)	See Figure 5		3		ns

† All typical values are at V_{CC} = 5 V, T_A = 25°C.

‡ C_{pd} determines the no-load dynamic current consumption; I_S = C_{pd} · V_{CC} · f + I_{CC}.

NOTE 2: This specification applies to any 5°C band within the operating temperature range.

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transceiver switching characteristics over recommended ranges of operating conditions

PARAMETER		TEST CONDITIONS	MIN	MAX	UNIT
$t_{en}(TXL)$	Enable time, transmit-to-receive to low-level output	See Figure 6		80	ns
$t_{en}(TXH)$	Enable time, transmit-to-receive to high-level output			80	ns
$t_{en}(RXL)$	Enable time, receive-to-transmit to low-level output			150	ns
$t_{en}(RXH)$	Enable time, receive-to-transmit to high-level output			150	ns
t_{su}	Setup time, WRAP1 or WRAP2 before active input(s) or output(s)			150	ns

thermal characteristics

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\theta JA}$	Junction-to-free-air thermal resistance	Board mounted, No air flow		50		°C/W
$R_{\theta JC}$	Junction-to-case thermal resistance			12		°C/W

PARAMETER MEASUREMENT INFORMATION

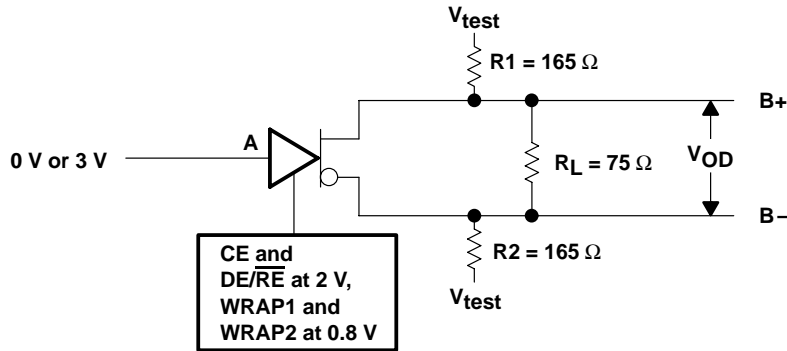
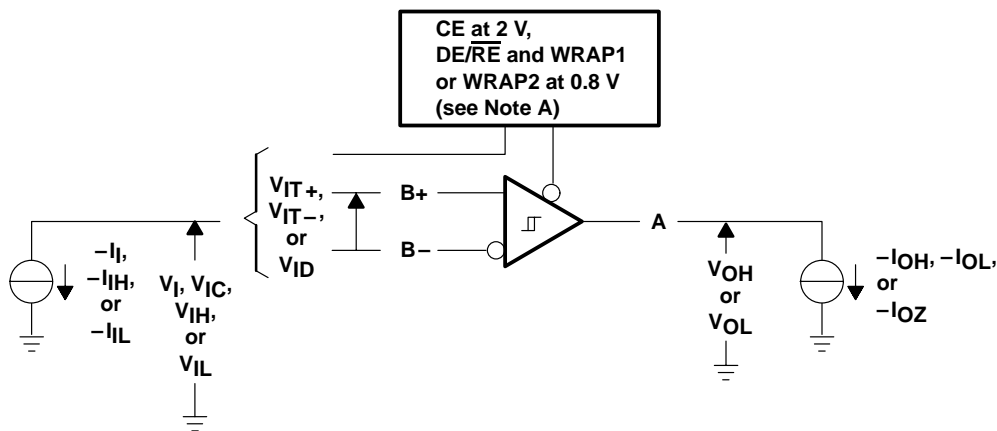


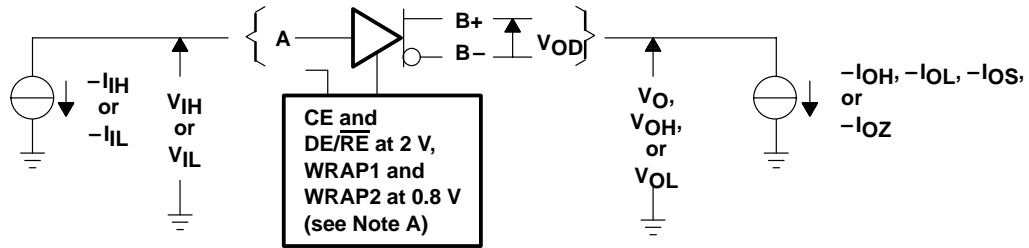
Figure 1. Driver V_{OD} Test Circuit



NOTE A: For the I_{OZ} measurement, CE is at 0.8 V.

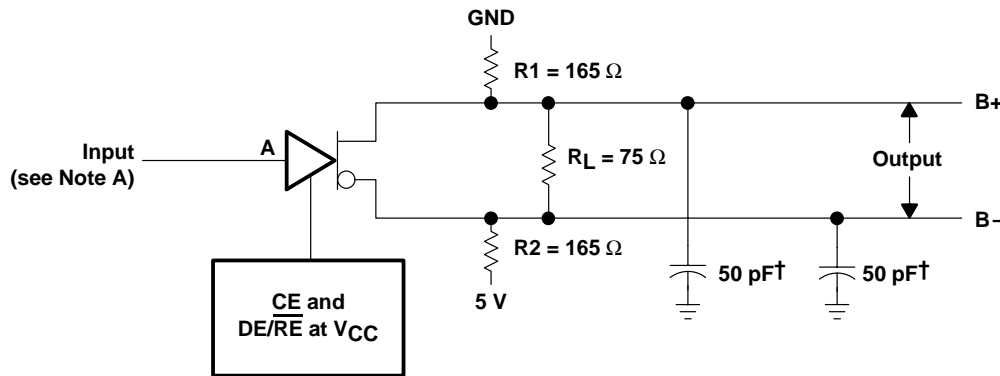
Figure 2. Receiver Test Circuit and Input Conditions

PARAMETER MEASUREMENT INFORMATION

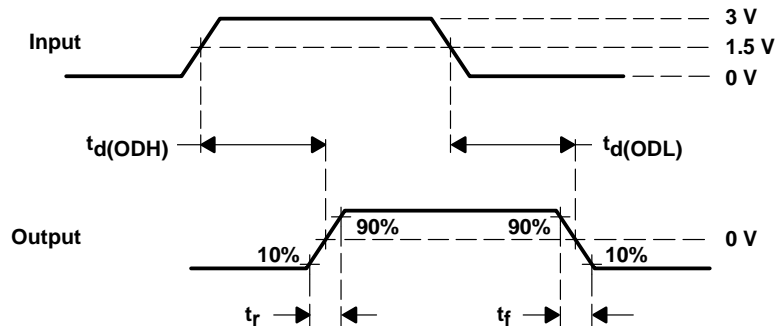


NOTE A: For the I_{OZ} test, the CE input is at 0.8 V.

Figure 3. Driver Test and Input Conditions



TEST CIRCUIT



VOLTAGE WAVEFORMS

† Includes probe and jig capacitance.

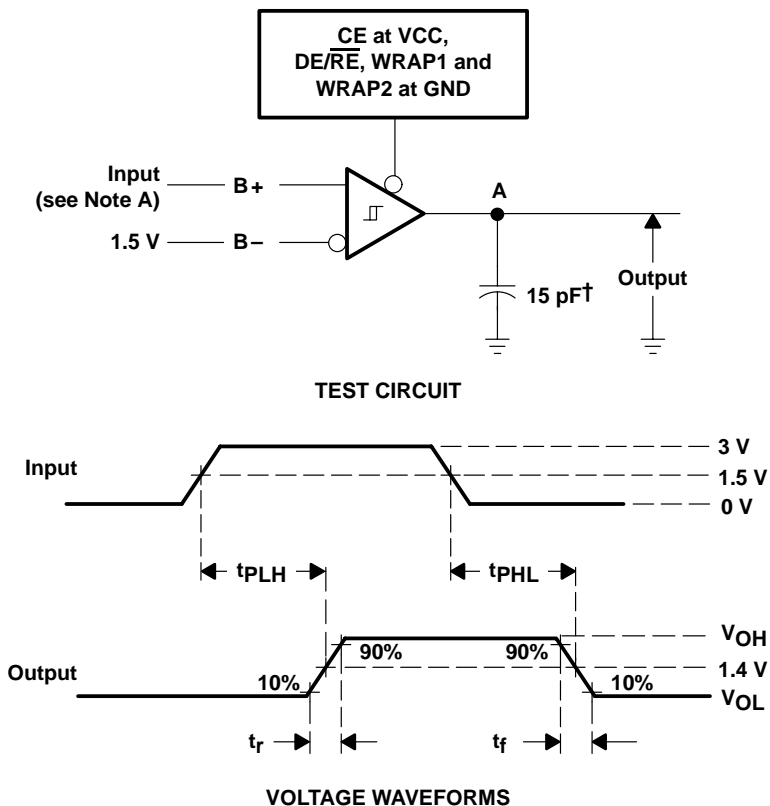
NOTE A: The input is provided by a pulse generator with an output of 0 to 3 V, PRR of 1 MHz, 50% duty cycle, t_r and $t_f < 6$ ns, and $Z_O = 50 \Omega$.

Figure 4. Driver Propagation Delay Time Test Circuit and Waveforms

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PARAMETER MEASUREMENT INFORMATION

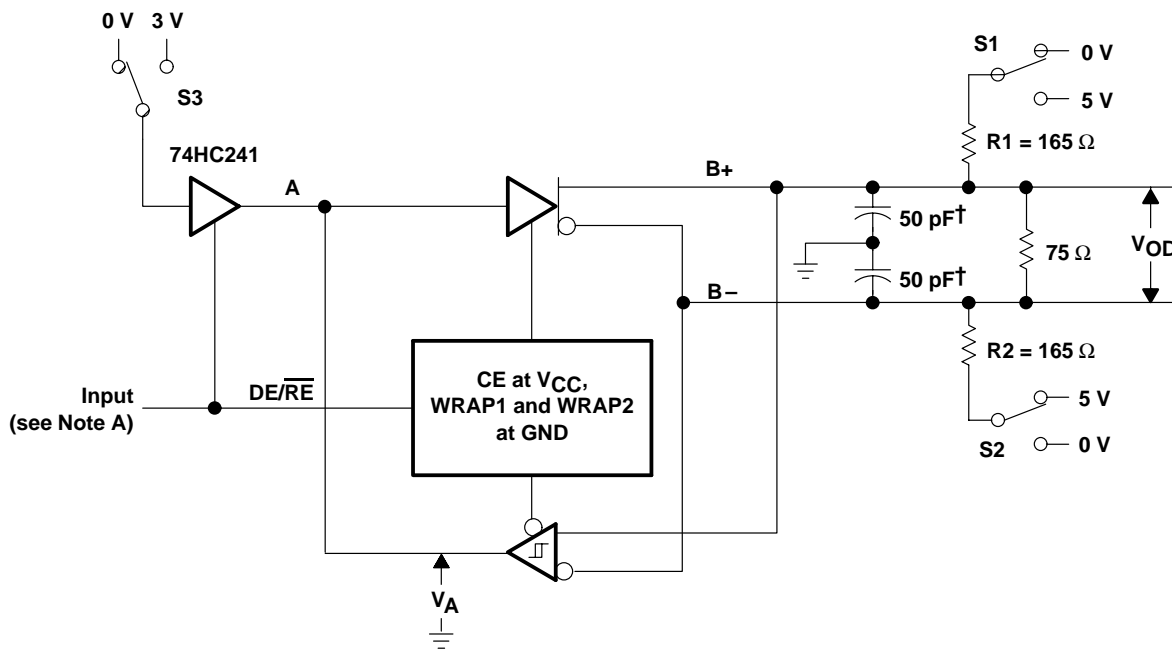


† Includes probe and jig capacitance.

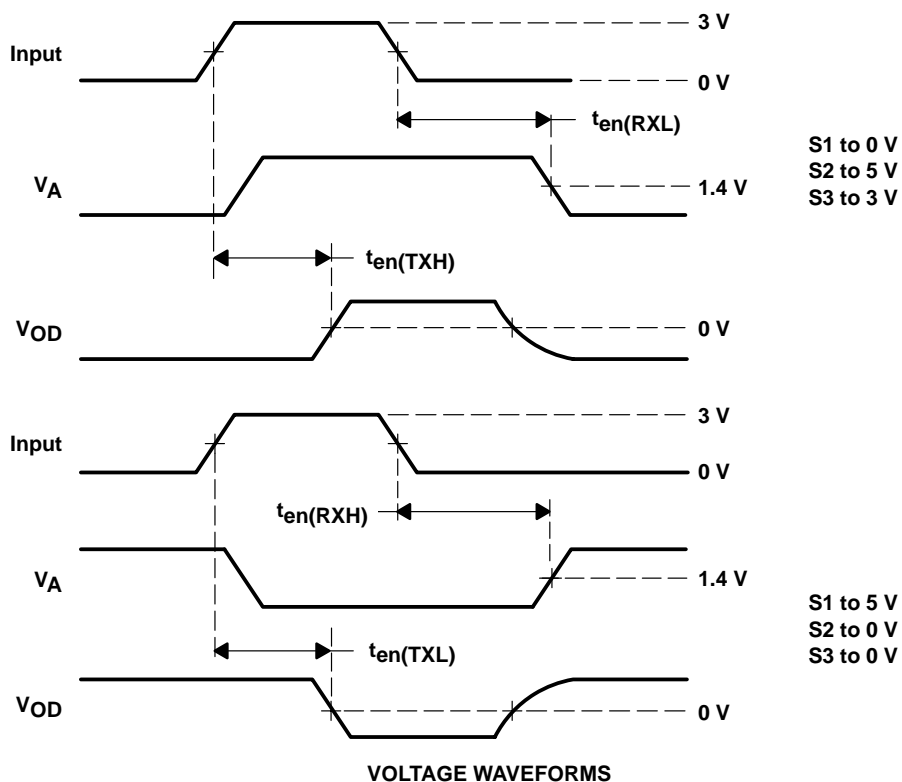
NOTE A: The input is provided by a pulse generator with an output of 0 to 3 V, PRR of 1 MHz, 50% duty cycle, t_r and t_f < 6 ns, and Z_O = 50 Ω.

Figure 5. Receiver Propagation Delay Time Test Circuit and Waveforms

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT



VOLTAGE WAVEFORMS

† Includes probe and jig capacitance.

NOTE A: The input is provided by a pulse generator with an output of 0 to 3 V, PRR of 1 MHz, 50% duty cycle, t_r and $t_f < 6$ ns, and $Z_O = 50 \Omega$.

Figure 6. Enable Time Test Circuit and Voltage Waveforms

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TYPICAL CHARACTERISTICS

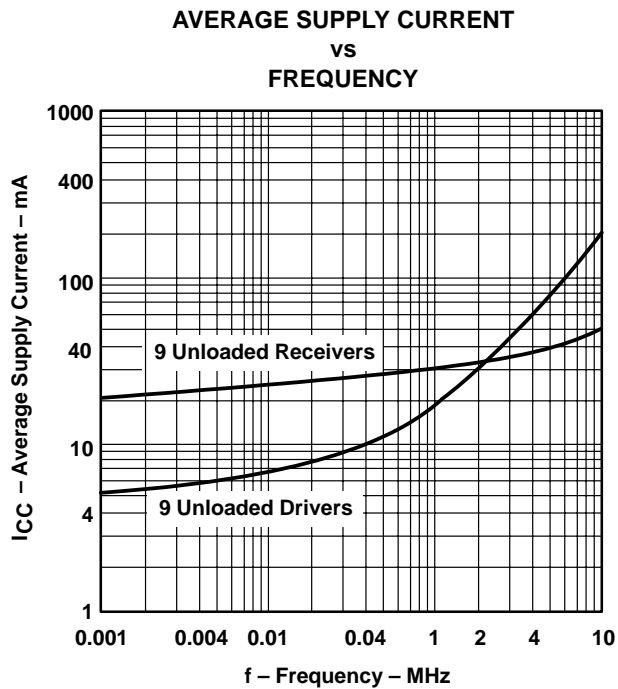


Figure 7

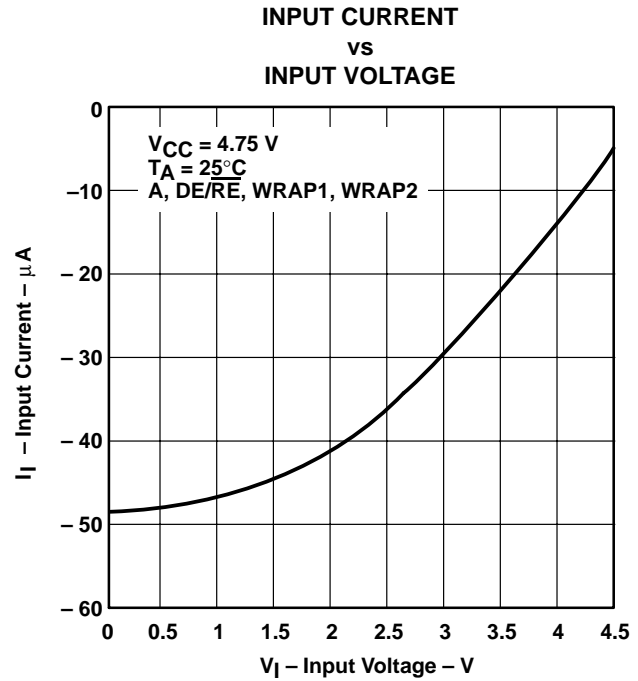


Figure 8

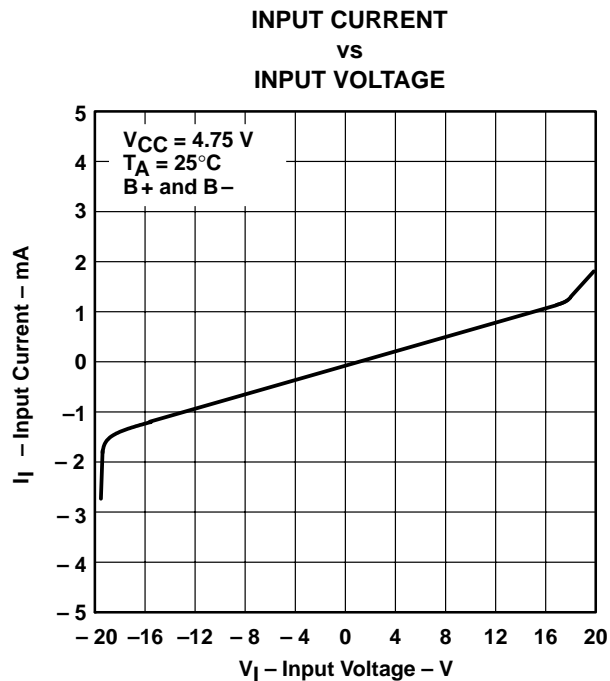
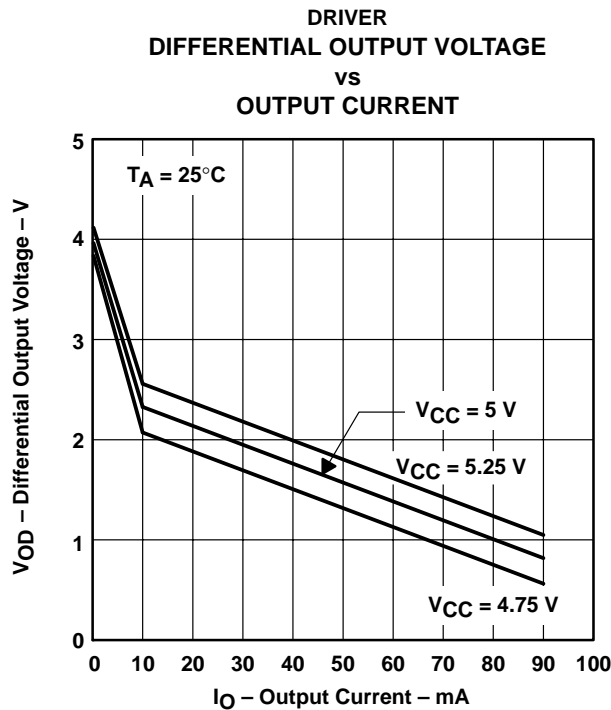
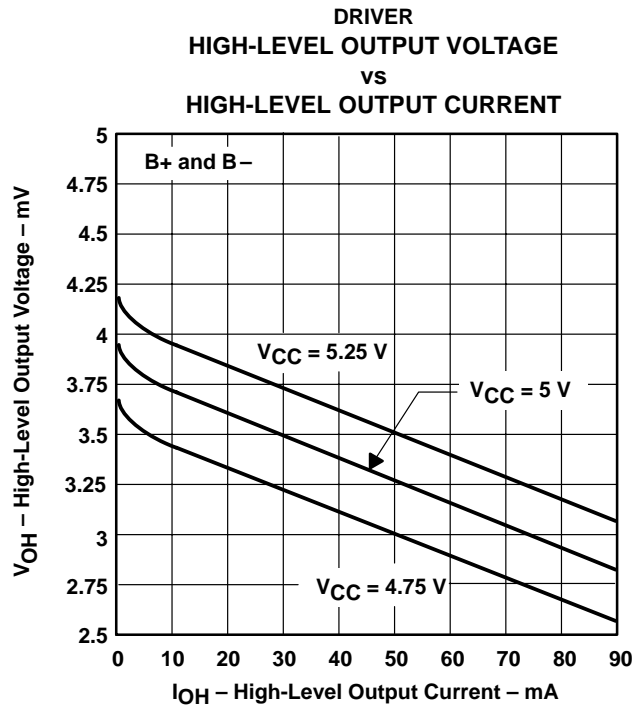
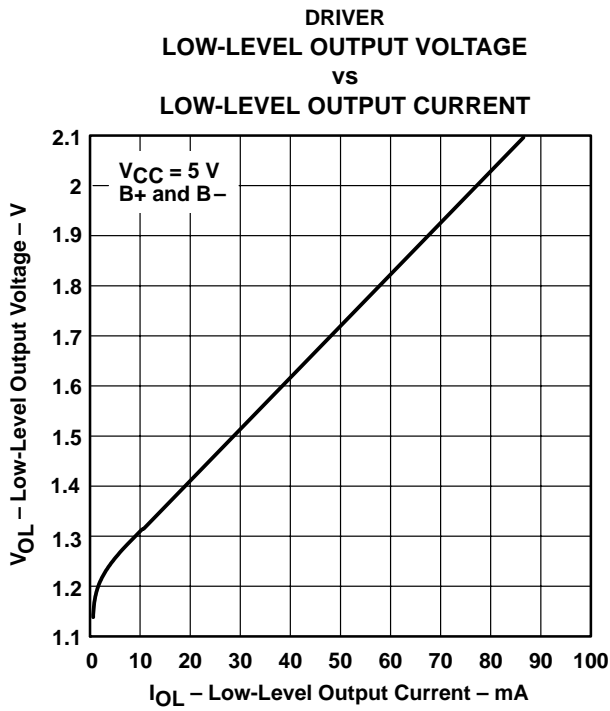


Figure 9

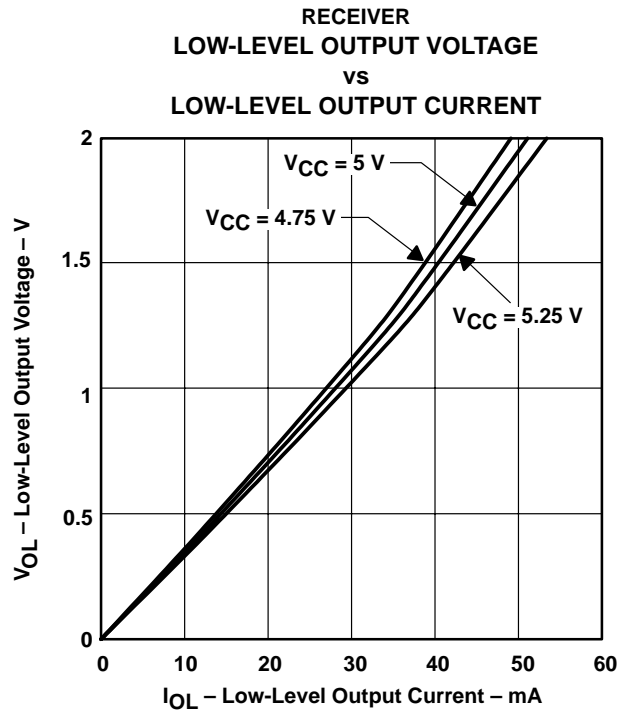
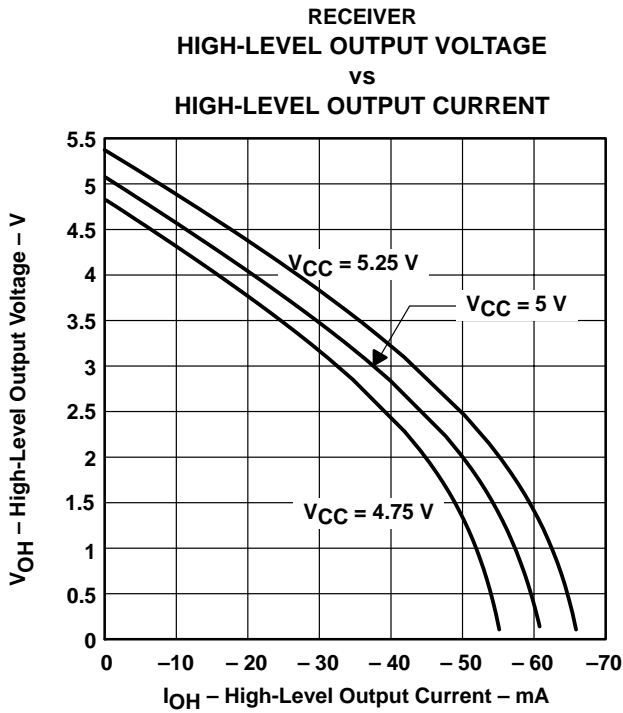
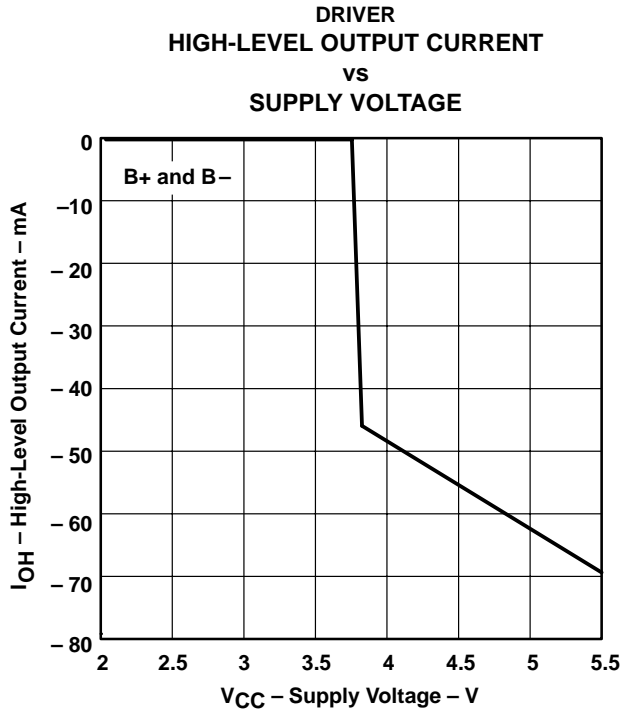
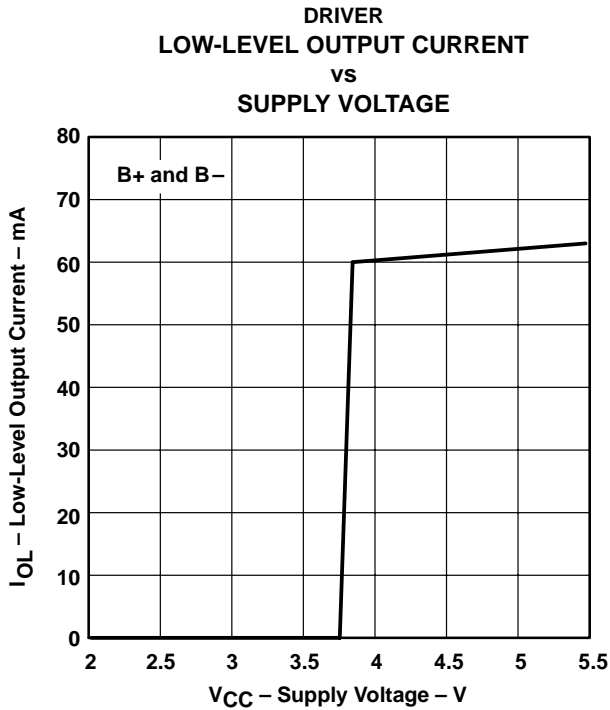
TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS



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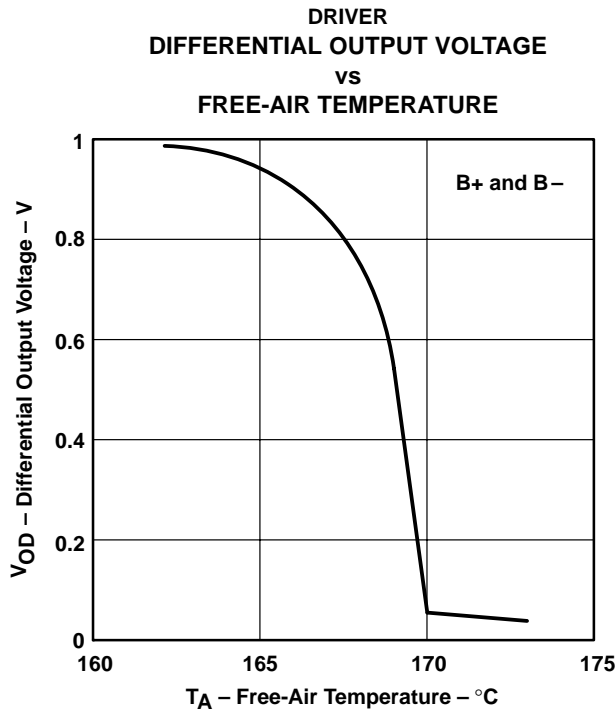


Figure 17

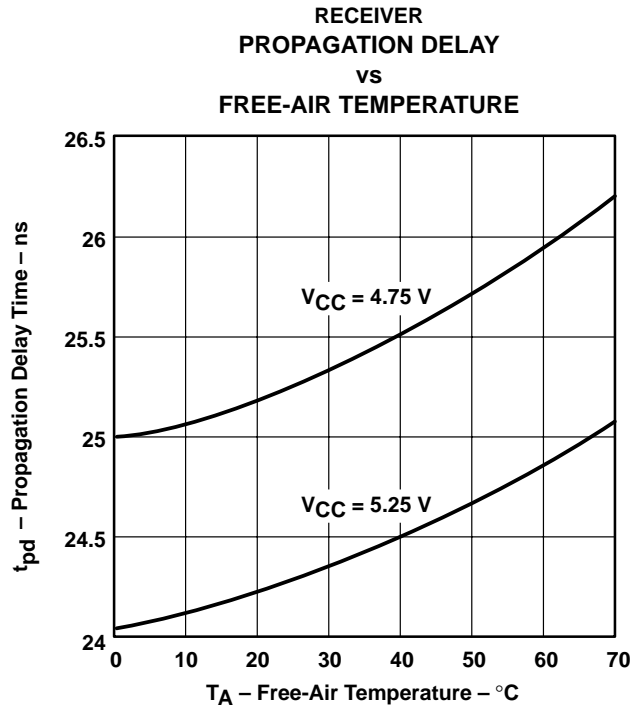


Figure 18

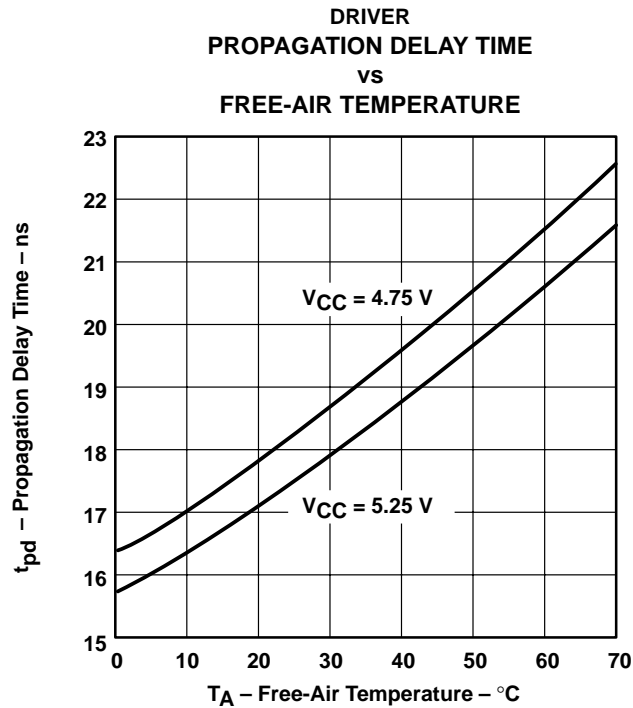


Figure 19

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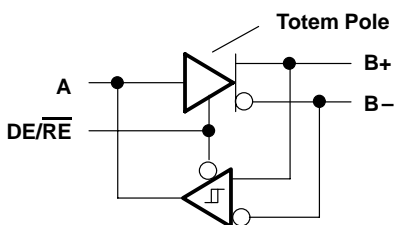
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APPLICATION INFORMATION

function tables

Table 1. Channel Configuration for Totem Pole Circuit

CE is high,
WRAP1 or WRAP2 is low



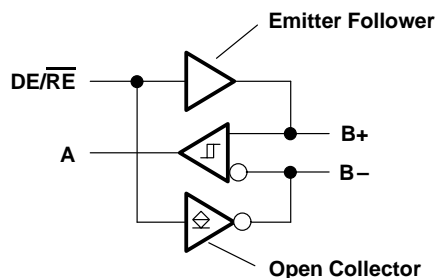
INPUTS				OUTPUTS		
DE/RE	A	B+†	B-†	A	B+	B-
L	X	L	H	L	Z	Z
L	X	H	L	H	Z	Z
H	L	X	X	Z	L	H
H	H	X	X	Z	H	L

H = high level L = low level X = irrelevant Z = high impedance

† An H in this column represents a voltage 200 mV higher than the other bus input. An L represents a voltage 200 mV lower than the other bus input. Any voltage less than 200 mV results in an indeterminate receiver output.

Table 2. Channel Configuration for Emitter Follower Circuit

CE is high,
WRAP1 or WRAP2 is high



INPUTS			OUTPUTS		
DE/RE	B+	B-	A	B+	B-
L	L	H	L	Z	Z
L	H	L	H	Z	Z
H	X	X	H	H	L
H	X	X	H	H	L

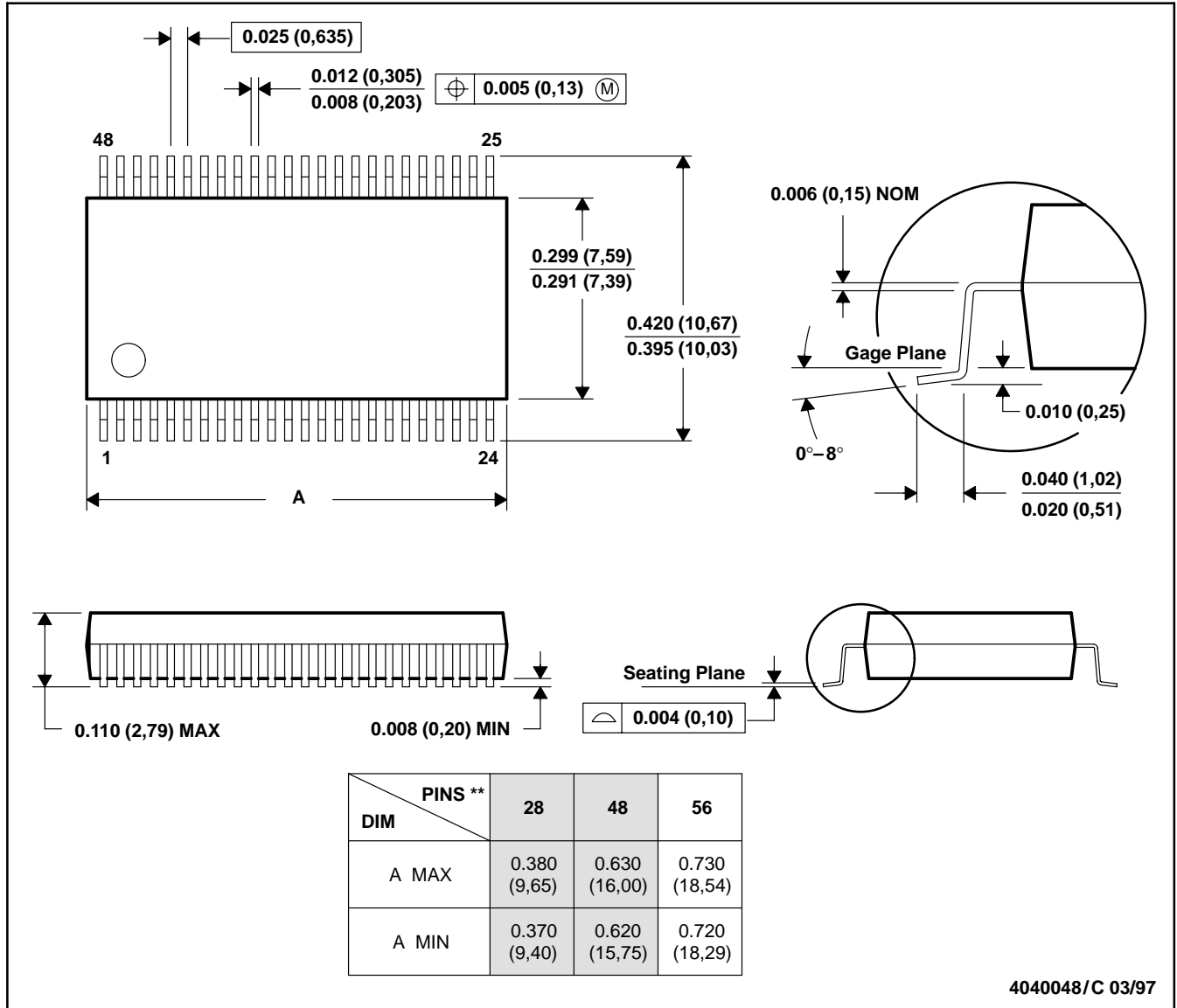
H = high level L = low level X = irrelevant Z = high impedance

MECHANICAL INFORMATION

DL (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 D. Falls within JEDEC MO-118

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